

B8100 110,59 MHz

duroplast package DIP18D

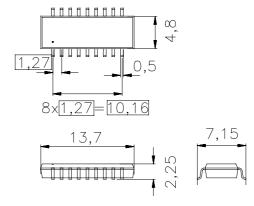
Data Sheet

Features

- IF filter for cordless application
- Channel selection in DECT system
- Low group delay ripple
- Surface Mounted Technology (SMT)
- Standard IC small outline (SO) package
- Balanced and unbalanced operation possible

Terminals

Tinned CuFe alloy



Dimensions in mm, approx. weight 0,4 g

Pin configuration

7 Input

8 Input ground or balanced input

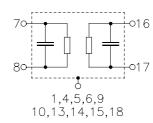
16 Output

17 Output ground or balanced output

1,4,5,6,9,10 Chip carrier – ground

13,14,15,18

2,3,11,12 not connected



Туре	Ordering code	Marking and Package according to	Packing according to		
B8100	B39111-B8100-L100	C61157-A2-A4	F61074-V8058-Z000		

Electrostatic Sensitive Device (ESD)

Maximum ratings

Operable temperature range	T	- 25/+ 65	°C
Storage temperature range	$T_{ m stg}$	- 40/+ 85	°C
DC voltage	$V_{\rm DC}$	5	V
Source power	P_{s}	10	dBm



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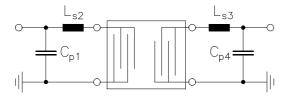
Characteristics

Operating temperature range: $T = +25 \,^{\circ}\text{C}$

Terminating source impedance: $Z_{\rm S} = 50 \,\Omega \,(\,600 \,\Omega \,||\,240 \,{\rm nH^*})$ Terminating load impedance: $Z_{\rm L} = 50 \,\Omega \,(\,140 \,\Omega \,||\,110 \,{\rm nH^*})$

		min.	typ.	max.	
Nominal frequency	f _N	_	110,59	_	MHz
Center frequency (center frequency between 10 dB points)	$f_{\rm C}$	110,48	110,59	110,70	MHz
Insertion attenuation at f_N	α_{N}		20,9	22,4	dB
(including losses in matching network)	11	_	(13,5*)	(15,0*)	dB
Passband width	B_{3dB}	_	1,28		MHz
	B _{30dB}	_	2,40	_	MHz
Group delay ripple (p-p)	Δτ				
$f_{\rm N}$ - 600 kHz $f_{\rm N}$ + 600 kHz		_	180	250	ns
		_	(300*)	(400*)	ns
Relative attenuation (relative to α_N)	$lpha_{rel}$				
f_{N} - 576 kHz f_{N} + 576 kHz		_	2,0	4,0	dB
$f_{\rm N} \pm 576 \text{ kHz}$ $f_{\rm N} \pm 700 \text{ kHz}$		_	_	10,0	dB
$f_{\rm N} \pm 1,6 {\rm MHz} f_{\rm N} \pm 3,1 {\rm MHz}$		32	38	_	dB
$f_{\text{N}} \pm 3,1 \text{ MHz}$ $f_{\text{N}} \pm 4,6 \text{ MHz}$		40	44	_	dB
$f_{\text{N}} \pm 4.6 \text{ MHz}$ $f_{\text{N}} \pm 20 \text{ MHz}$		45	50	_	dB
<i>f</i> _N ± 1,728 MHz		32	38	_	dB
$f_{\rm N} \pm 2 \times 1,728 \rm MHz$		42	47	_	dB
$f_{\rm N} \pm 3 \times 1,728 \text{ MHz}$		48	53	_	dB
Impedance at f_N					
Input: $Z_{IN} = R_{IN} \parallel C_{IN}$			600 8,5	_	$\Omega \parallel pF$
Output: $Z_{OUT} = R_{OUT} C_{OUT}$		_	140 19,0	_	Ω pF
Temperature coefficient of frequency	TC_{f}	_	- 18	_	ppm/K

^{*)} with matching network to 50 Ω (element values depend on PCB layout):



 $\begin{array}{lll} C_{p1} & = & 0 & pF \\ L_{s2} & = 220 & nH \\ L_{s3} & = 120 & nH \\ C_{p4} & = & 22 & pF \end{array}$

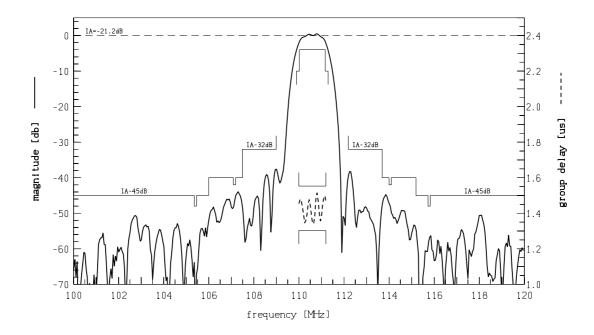
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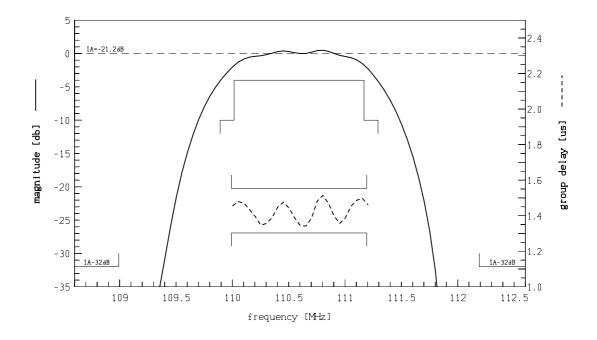
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Transfer function:



Transfer function (pass band):





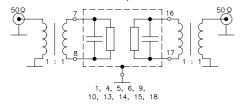
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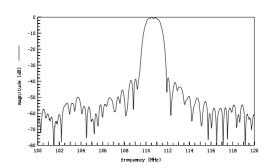
Application Note

Recommended Pin Configurations:

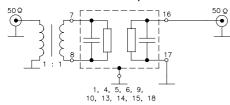
For optimum performance use the following pin configurations.

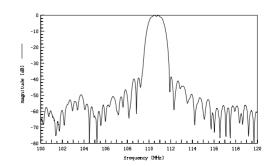
Balanced-balanced operation:



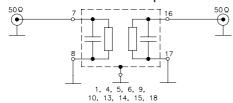


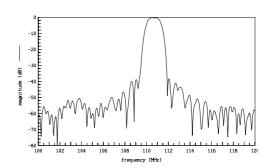
Balanced-unbalanced operation:





Unbalanced-unbalanced operation





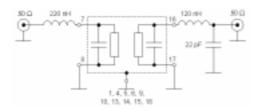


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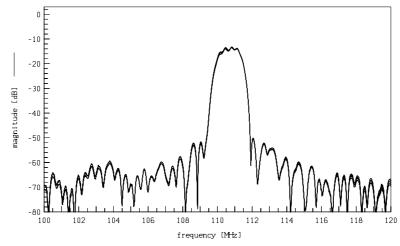
Application Note

Matching Stability / Variation of the Matching Network:

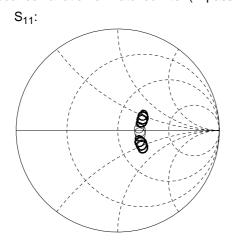
All matching-elements changed by $\pm 10\%$ (simulation).

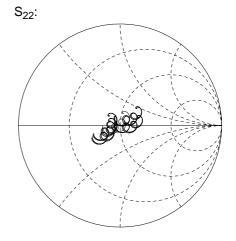


Transfer function of matched filter (S₂₁):



Impedance variation of matched filter (in passband):





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OFW EM CP Jun 30, 1997